

FORM PTO-1449

LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANT'S INFORMATION DISCLOSURE
STATEMENT

(Use several sheets if necessary)

ATTY. DOCKET NO.

10002343-1

SERIAL NO.

APPLICANT

Robert Davidson

FILING DATE

Herewith

GROUP

Ukn.

JCS11 U.S. PTO
09/16/242

01/12/01

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
MJC	1A	4,427,886	1/1984	Martin et al.	250	310
MJC	1B	4,534,016	8/1985	Kirkpatrick et al.	365	128
MJC	1C	4,600,839	7/1986	Ichihashi et al.	250	310
MJC	1D	4,760,567	7/1988	Crewe	369	101
MJC	1E	5,402,410	3/1995	Yoshimura et al.	369	275.1
MJC	1F	5,557,596	9/1996	Gibson et al.	369	101
	1G					
	1H					
	1I					
	1J					
	1K					

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	TRANSLATION	
							YES	NO
	1L							
	1M							
	1N							
	1O							
	1P							

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

MJC	1Q	E. Huber et al., "Laser-Induced Crystallization of Amorphous GeTe: A Time-Resolved Study," Physics Review B, Vol. 36, No. 3, pp. 1595-1604 (July 15, 1987).	✓
MJC	1R	R.T. Howe et al., "Silicon Micromechanics: Sensors and Actuators on a Chip," IEEE Spectrum, pp. 35 (July 1990).	✓
MJC	1S	V.P. Jaecklin et al., "Novel Polysilicon Comb Actuators for X-Y Stages", Proceedings of MicroElectro Mechanical Systems," pp. 147-149 (1992).	

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DATE CONSIDERED

11/19/03

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EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
	2A					
	2B					
	2C					
	2D					
	2E					
	2F					
	2G					
	2H					
	2I					
	2J					
	2K					

FOREIGN PATENT DOCUMENTS

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							YES	NO
	2L							
	2M							
	2N							
	2O							
	2P							

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

MJC	2Q	G.W. Jones, "Silicon Field Emission Transistors and Diodes," IEEE Trans. Components, Hybrids and Manufacturing Technology, Vol. 15, pp. 1051-1055 (1992).
MJC	2R	C.A. Spindt et al., "Physical Properties of Thin-Film Field Emission Cathodes with Molybdenum Cones," Journal of Applied Physics, Vol. 47, No. 12, pp. 5248-5263 (December 19).
MJC	2S	B.G. Yacobi, "Electron-Beam-Induced Information Storage in Hydrogenated Amorphous Silicon Device," Journal of Applied Physics Letters, Vol. 44, No. 7, pp. 695-697 (April 1984).

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DATE CONSIDERED